

DESCRIPTION

METHOD FOR PRODUCING SOLID ELECTROLYTIC CAPACITOR

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TECHNICAL FIELD

The present invention relates to a method for manufacturing solid electrolytic capacitor for use in various kinds of electronic apparatus.

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BACKGROUND ART

In line with the recent trends of downsizing and introduction of higher frequencies among the electronic apparatus, capacitors are requested to be compact yet to have a larger capacitance, a lower ESR (Equivalent Series Resistance) and a lower ESL (Equivalent Series Inductance).

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As to the technology for increasing capacitance of a solid electrolytic capacitor (hereinafter referred to as SEC), the USP 5377073 and the Japanese Patent Laid-open No. H11-274002 disclose a technology of laminating capacitor elements in a chip-type capacitor. Thus the conventional SECs can be increased in the capacitance, and improved in the ESR.

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However, when mounting the conventional SECs on the surface of a circuit board like semiconductor components, the SECs need the help of external terminals for connection. This way of connection poses a limitation in the improvement of ESL. In order to further reduce the ESL, shapes and length of terminals for electrical connection and the wirings need to be

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streamlined. The present invention addresses the above problems, and aims to offer a method for manufacturing large capacitance SECs that can be connected direct with semiconductor components and implement a superior

high frequency response.

DISCLOSURE OF THE INVENTION

According to a first aspect of the present invention, there is provided a method for manufacturing solid electrolytic capacitor including the steps of: forming a porous portion on one of the surfaces of an aluminum foil, forming a dielectric layer on said porous portion, forming a through hole in said aluminum foil at a certain specific location, forming an insulation layer on said aluminum foil to cover both the other surface that is opposite to the one having said porous portion and the inner wall surface of said through hole, forming a solid electrolytic layer on said dielectric layer, forming a through hole electrode in said through hole, forming a collector layer on said solid electrolytic layer, forming an opening at a certain specific location of said insulating layer provided on said aluminum foil, and providing a connection terminal in said opening and on the exposed surface of said through hole electrode, respectively. Since the connection terminals provided in the opening of insulation layer and on the exposed surface of through hole electrode are disposed on a same plane, the SEC can be connected direct with semiconductor component and offers a superior high frequency characteristic.

According to a second aspect of the present invention, there is provided a method for manufacturing solid electrolytic capacitor including the steps of: forming a porous portion on one of the surfaces of an aluminum foil, forming a dielectric layer on said porous portion, forming a through hole in said aluminum foil at a certain specific location, forming a resist portion on the other surface of the aluminum foil that is opposite to the one having said porous portion at a certain specific location, forming an insulation layer on said aluminum foil to cover both the other surface that is opposite to the one having said porous portion and the inner wall surface of said through hole, forming a solid electrolytic layer on said dielectric layer, forming a through

hole electrode in said through hole, forming a collector layer on said solid electrolytic layer, forming an opening in said insulation layer disposed on said aluminum foil at a certain specific location by peeling said resist portion off, and providing a connection terminal at said opening of said insulation layer and on exposed surface of said through hole electrode, respectively.

According to a third aspect of the present invention, there is provided a method for manufacturing solid electrolytic capacitor including the steps of: forming a porous portion on one of the surfaces of an aluminum foil, forming a dielectric layer on said porous portion, forming a through hole in said aluminum foil at a certain specific location, forming an insulation layer on said aluminum foil to cover both the other surface that is opposite to the one having said porous portion and the inner wall surface of said through hole, forming a resist film covering the entire surface of said insulation layer, forming a solid electrolytic layer on said dielectric layer, forming a through hole electrode in said through hole, peeling said resist film off, forming a collector layer on said solid electrolytic layer, forming an opening in said insulation layer disposed on said aluminum foil at a certain specific location, and providing a connection terminal at said opening of said insulation layer and on exposed surface of said through hole electrode, respectively.

According to a fourth aspect of the present invention, there is provided a method for manufacturing solid electrolytic capacitor including the steps of: forming a porous portion on one of the surfaces of an aluminum foil, forming a dielectric layer on said porous portion, forming a through hole in said aluminum foil at a certain specific location, forming a resist portion on said aluminum foil at a certain specific location, forming an insulation layer on said aluminum foil to cover both the other surface that is opposite to the one having said porous portion and the inner wall surface of said through hole, forming a resist film covering the entire surface of said insulation layer, forming a solid electrolytic layer on said dielectric layer, forming a through hole electrode in said through hole, peeling said resist film off, forming a collector layer on said solid electrolytic layer, forming an opening in said

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insulation layer disposed on said aluminum foil at a certain specific location by peeling said resist portion off, and providing a connection terminal at said opening of said insulation layer and on exposed surface of said through hole electrode, respectively.

According to a fifth aspect of the present invention, there is provided a method for manufacturing solid electrolytic capacitor including the steps of: forming a porous portion on one of the surfaces of an aluminum foil, forming a dielectric layer on said porous portion, forming a through hole in said aluminum foil at a certain specific location, forming an insulation layer on said aluminum foil to cover both the other surface that is opposite to the one having said porous portion and the inner wall surface of said through hole, forming a through hole electrode in said through hole, forming a solid electrolytic layer on said dielectric layer, forming a collector layer on said solid electrolytic layer, forming an opening in said insulation layer disposed on said aluminum foil at a certain specific location, and providing a connection terminal at said opening of said insulation layer and on exposed surface of said through hole electrode, respectively.

According to a sixth aspect of the present invention, there is provided a method for manufacturing solid electrolytic capacitor including the steps of: forming a porous portion on one of the surfaces of an aluminum foil, forming a dielectric layer on said porous portion, forming a first through hole in said aluminum foil at a certain specific location, forming an insulation portion on said aluminum foil to cover the other surface that is opposite to the one having said porous portion and the inside of said first through hole, forming a solid electrolytic layer on said dielectric layer, forming a second through hole in said insulation portion, forming a through hole electrode in said second through hole, forming a collector layer on said solid electrolytic layer, forming an opening in said insulation layer disposed on said aluminum foil at a certain specific location, and providing a connection terminal at said opening of said insulation layer and on exposed surface of said through hole electrode, respectively.

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is a perspective view of an SEC manufactured in accordance with a first exemplary embodiment of the present invention.

FIG. 2 is a cross sectional view of an SEC in the first embodiment.

FIG. 3 is a cross sectional magnified view of an SEC, showing the key portion in the first embodiment.

FIG. 4 is a cross sectional view of aluminum foil of an SEC, showing a

state after chamfering in the first embodiment.

FIG. 5 is a cross sectional view of aluminum foil of an SEC, showing a state after an insulation layer was formed covering the non-porous surface and the inner wall surface of through hole in the first embodiment.

5 FIG. 6 is a cross sectional view of aluminum foil of an SEC, showing a state after a solid electrolytic layer was formed on dielectric layer in the first embodiment.

FIG. 7 is a cross sectional view of an SEC, showing a state after a through hole electrode was formed in the through hole in the first
10 embodiment.

FIG. 8 is a cross sectional view of an SEC, showing a state after a collector layer was formed on solid electrolytic layer in the first embodiment.

FIG. 9 is a cross sectional view of an SEC, showing a state after an opening was formed in the insulation layer in the first embodiment.

15 FIG. 10 is a cross sectional view of an SEC, showing a state after a connection terminal was formed in the opening in the first embodiment.

FIG. 11 is a cross sectional view of capacitor elements of an SEC, showing a state after a package was provided in the first embodiment.

FIG. 12 is a cross sectional view of an SEC, showing a state after
20 external terminals were provided on the package, as well as connection bumps, in the first embodiment.

FIG. 13 is a cross sectional view of an SEC, showing a state after a resist film was provided on the insulation layer in a second exemplary embodiment.

25 FIG. 14 is a cross sectional view of an SEC, showing a state of resist film after patterning in the second embodiment.

FIG. 15 is a cross sectional view of an SEC, showing a state after a

through hole electrode was formed in the through hole in a third exemplary embodiment.

FIG. 16 is a cross sectional view of an SEC, showing a state after a solid electrolytic layer was formed on the dielectric layer in the third
5 embodiment.

FIG. 17 is a cross sectional view of an SEC, showing a state after an insulation layer was formed on the non-porous surface of aluminum foil and an insulation portion was provided in the through hole in a fourth exemplary embodiment.

10 FIG. 18 is a cross sectional view of an SEC, showing a state after a solid electrolytic layer was formed on the dielectric layer in the fourth embodiment.

FIG. 19 is a cross sectional view of an SEC, showing a state after a through hole was formed in the insulation portion in the fourth embodiment.
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BEST MODE FOR CARRYING OUT THE INVENTION

A solid electrolytic capacitor (SEC) and the method of manufacture in accordance with exemplary embodiments of the present invention are described referring to the drawings. The drawings are aimed to present the
20 concepts, not to exhibit precise dimensions.

(Embodiment 1)

Reference is made to FIG. 1 - FIG. 3, in a sheet-formed capacitor element 1, one of the surfaces of an aluminum foil 3 is made porous by etching or the like process, a dielectric layer 2 is formed on the porous portion, and a
25 through hole 4 is formed in the aluminum foil 3 at a certain specific location. An insulation layer 5 is provided to cover the other surface, viz. non-porous surface, of the aluminum foil 3 and the inner wall surface of through hole 4,

and a solid electrolytic layer 6 is formed on the dielectric layer 2. A through hole electrode 7 is formed in the through hole 4, and then a collector layer 8 is formed on the solid electrolytic layer 6. Next, the insulation layer 5 on aluminum foil 3 is provided with an opening 9 at a certain specific location, and the surface exposed by the opening 9 is provided with a connection terminal 10. The through hole electrode refers to an electrode formed in the through hole.

The capacitor element 1 thus structured is provided with a package 11 covering the side surfaces and the collector layer 8. A first external terminal 12, which is electrically connected with the aluminum foil 3, and a second external terminal 13, which is electrically connected with the collector layer 8, are provided on the package 11, and then a connection bump 14 is provided on the through hole electrode 7 and the connection terminal 10, respectively. A finished SEC is thus completed. In the following, a method for manufacturing SEC in the present invention is described referring to the drawings FIG. 4 through FIG. 12.

The aluminum foil 3 with dielectric layer 2 is provided by etching one of the surfaces of an aluminum foil 3 to make it porous, and then forming a dielectric oxide film thereon through anode oxidization in a electrolytic solution. And then, the aluminum foil 3 is provided with a through hole 4 at a certain specific location, as shown in FIG. 4.

The through holes can be formed altogether by means of a wet etching process. Besides the wet etching, a finer through hole of 100 μ m or smaller can be formed at a high precision level by using a laser beam machining, a punching method, a drilling method, an electric discharge machining, or the like means. The above methods are applicable to any kinds of materials. When forming the through holes by wet etching process, an aluminum foil 3 is

etched after the foil is provided at both surfaces with resist film having openings at places corresponding to the through holes, and then the resist film is removed. If edge of the through hole at the surface to be facing to dielectric layer 2 is chamfered by means of wet etching or the like process, it contributes to further improve the reliability of an insulation layer, which will be provided at a later step. Next, by applying an insulating film through electrodeposition, an insulation layer 5 is formed to cover the other surface, viz. non-porous surface, of the aluminum foil 3 and the inner wall surface of through hole 4, as shown in FIG. 5. Although the electrodeposition provides an even and intense insulation layer, there is a possibility that the thickness of the layer turns out to be slightly thinner at the edge of through hole 4 facing the dielectric layer 2. The edge chamfering is effective for eliminating the risk and implementing a higher insulating reliability. Application of an insulating resin containing a micro gel of high edge-covering property, carbon particles and titanium oxide particles through electrodeposition is quite advantageous. The micro gel referred to in the present example is a polymer added with a polymer substance of particle diameter $10\mu\text{m}$ or smaller to increase the viscosity and lower the fluidity; thereby improving the edge-covering property. However, if a resin mixture of high edge-covering property is electrodeposited onto the inner wall surface of fine through hole of $100\mu\text{m}$ or smaller, the deposited layer may become too thick and clog the through hole. Therefore, it is advised to split the electrodeposition into two stages; first attaching a thin film of a high resistivity resin and then an insulating resin which is a mixture of a micro gel of high edge-covering property, carbon particles and titanium oxide particles. By so doing, an insulation layer 5 of low failure rate is provided on the inner wall surface of through hole. Then, as shown in FIG. 6, a solid electrolytic layer 6 is formed on the dielectric layer

2. The solid electrolytic layer 6 can be formed through a chemical polymerization or an electrolytic polymerization of a π electron conjugated polymer such as polypyrrole, polythiophene, and/or a composite material containing a conducting polymer other than that; or by combining these.

5 Besides the above-described process, it can be formed by applying a suspension of conducting polymer and drying it, and then conducting an electrolytic polymerization; or, by impregnating it with manganese nitrate and then heat-decomposing it to generate manganese dioxide, and then conducting an electrolytic polymerization. A further established technology

10 available for forming a solid electrolytic layer is forming manganese dioxide by heat-decomposing manganese nitrate. Thus, the productivity and the reliability can be improved by selecting an appropriate process that provides an intense layer at an optional thickness.

Next, a process for forming a through hole electrode 7 in the through

15 hole 4, as shown in FIG. 7, is described. The through hole is filled with a conducting adhesive substance such as Ag paste, Cu paste, etc. containing conductive particles; and then it is cured to form the through hole electrode 7. And then, a collector layer 8 is formed on the solid electrolytic layer 6, as shown in FIG. 8. The collector layer 8 is formed by using a suspension of

20 carbon particles and a conducting adhesive material containing a silver past as the main ingredient, into a laminate structure of a carbon layer and a silver paste layer. The structure efficiently makes the electrical charges available. Then, as shown in FIG. 9, the insulation layer 5 formed on the other surface of aluminum foil 3 is provided with an opening 9 at a certain specific location, by

25 means of YAG laser or other process such as grinding. Besides the above method, the opening 9 can be formed also by other process; namely, providing a resist portion on the aluminum foil 3 before formation of insulation layer 5

at a certain specific place on the non-porous surface, and forming a collector layer 8 and an insulation layer 5, and then removing the resist portion. Then, a connection terminal 10 is formed on the surface exposed through the opening 9 of insulation layer 5, as shown in FIG. 10, using a conductive
5 adhesive substance, or by an electroplating or electroless plating. The capacitor element 1 is covered with an epoxy resin package 11, as shown in FIG. 11, for protecting it from humidity and stress from outside and ensuring good electrical insulation and increasing the reliability. The package 11 is provided with a first external terminal 12, which is electrically connected with
10 the aluminum foil 3, and a second external terminal 13, which is electrically connected with the collector layer 8, to complete a finished capacitor element 1.

The component of above-described structure functions as it is as an SEC of the present invention. However, it is preferred to further provide
15 connection bumps 14 on the connection terminal 10 and the through hole electrode 7, in order to raise the reliability in electrical connection with a semiconductor component or the like electronic component, and to improve the electrical performance.

The SECs manufactured in accordance with the above-described
20 manufacturing process have the connection terminals 10 and the connection bumps 14 disposed respectively on a same plane. Thus the present invention offers a method for manufacturing SECs that can be connected direct with semiconductor components, and superior in the high frequency characteristic.

(Embodiment 2)

25 FIG. 13 and FIG. 14 are the drawings used to describe the main process steps of manufacturing an SEC in accordance with a second exemplary embodiment of the present invention.

One of the surfaces of an aluminum foil 3 is etched for making it porous, and a dielectric layer 2 is formed on the porous portion. And then, a through hole 4 is formed in the aluminum foil 3 at a certain specific location, and an insulation layer 5 is provided to cover the other surface, viz. non-porous surface, of aluminum foil 3 and the inner wall surface of through hole 4.

So far, the procedure remains the same as in the embodiment 1. Next, when providing a solid electrolytic layer 6 on the dielectric layer 2, if the through hole has a diameter 80 μ m or larger the solid electrolytic layer 6 could form on the other surface, viz. non-porous surface, of aluminum foil 3.

10 In order to prevent this to happen, a photo sensitive resin is applied on the surface of insulation layer 5, as shown in FIG. 13, by using either of the methods among an immersion method, a spin coating process and a screen printing method. The photo sensitive resin is cured to form a resist film 15.

Instead, an adhesive organic film may be used for the resist film 15.

15 In this case, a film is attached on the surface of insulation layer 5. And then, the film is provided with a hole of certain specific dimensions at a location corresponding to the through hole 4, as shown in FIG. 14, by means of a photo processing or a mechanical machining. The film is used as the resist film. A solid electrolytic layer 6 and a through hole electrode 7 are provided in the same way as in the embodiment 1, and then the resist film 15 is removed.

20 Thus, no solid electrolytic layer 6 is formed on the other surface, viz. non-porous surface, of aluminum foil 3, and the positive electrode and the negative electrode are surely separated. Thereafter, in the same way as in the embodiment 1, a collector layer 8 is formed on the solid electrolytic layer 6, an

25 opening 9 is formed in the insulation layer 5 disposed on the other surface of aluminum foil 3 at a certain specific location, and a connection terminal 10 is provided at the opening 9 of insulation layer 5 and on the exposed surface of

through hole electrode 7, respectively. Thus in an SEC manufactured in accordance with the manufacturing method of the present embodiment 2, a possible spreading of the solid electrolytic layer onto the opening 9 of aluminum foil 3 is avoided, since the opening is formed at a later step, and the positive electrode and the negative electrode are certainly separated to each other.

(Embodiment 3)

FIG. 15 and FIG. 16 are the drawings used to describe the main process steps of manufacturing an SEC in accordance with a third exemplary embodiment of the present invention.

One of the surfaces of an aluminum foil 3 is etched for making it porous, and a dielectric layer 2 is formed on the porous portion. And then, a through hole 4 is formed in aluminum foil 3 at a certain specific location, and an insulation layer 5 is provided to cover the other surface, viz. non-porous surface, of aluminum foil 3 and the inner wall surface of through hole 4.

So far, the procedure remains the same as in the embodiment 1. Next, when providing a solid electrolytic layer 6 on the dielectric layer 2, if the through hole has a diameter 80 μ m or larger the solid electrolytic layer 6 could form on the other surface, viz. non-porous surface, of aluminum foil 3.

In order to prevent this to happen, a through hole electrode 7 is first formed in the through hole 4, as shown in FIG. 15.

The through hole electrode 7 is formed by filling a conductive adhesive substance such as Ag paste or Cu paste containing conductive particles, and curing it. And then, a solid electrolytic layer 6 is formed on the dielectric layer 2, as shown in FIG. 16. Therefore, no solid electrolytic layer 6 can be formed on the other surface, viz. non-porous surface, of aluminum foil 3. And then, a collector layer 8 is formed on the solid electrolytic layer 6 in the same

way as in the embodiment 1, and an opening 9 is formed in the insulation layer 5 covering the surface of aluminum foil 3 at a certain specific location by means of YAG laser, or the like process. The opening 9 can be formed instead by providing a resist portion beforehand on the non-porous surface of aluminum foil 3 using photo sensitive resin or the like material prior to formation of the insulation layer 5, and removing the resist portion after collector layer 8 is formed. And then, connection terminal 10 is provided on the exposed surface at the opening 9 and on the through hole electrode 7, respectively. Thus in an SEC manufactured in accordance with the manufacturing method of the present embodiment 2, a possible spreading of the solid electrolytic layer onto the opening 9 of aluminum foil 3 is avoided, since the opening is formed at a later step, and the positive electrode and the negative electrode are certainly separated to each other.

(Embodiment 4)

FIG. 17 and FIG. 18 are the drawings used to describe the main process steps of manufacturing an SEC in accordance with a fourth exemplary embodiment of the present invention.

One of the surfaces of an aluminum foil 3 is etched for making it porous, and a dielectric layer 2 is formed on the porous portion. And then, a first through hole 4 is formed in the aluminum foil 3 at a certain specific location. So far the procedure remains the same as in the embodiment 1. Next, an insulation layer 5 is formed to cover the other surface, viz. non-porous surface, of aluminum foil 3 and the inner wall surface of through hole 4. And then, a solid electrolytic layer 6 is provided on the dielectric layer 2. If the through hole has a diameter 80 μ m or larger, the solid electrolytic layer 6 could form on the other surface, viz. non-porous surface, of aluminum foil 3.

In order to prevent this to happen, an insulation layer 5 is formed on

the other surface, viz. non-porous surface, of aluminum foil 3, and an insulating portion 16 inside the first through hole, in the first place as shown in FIG. 17. The insulation layer 5 is formed in the same way as in the embodiment 1. The insulating portion 16 can be provided by
5 electrodepositing an easy-to-fill insulating resin for several times to fill the through hole, or screen-printing or potting an insulating resin. And then, as shown in FIG. 18, a solid electrolytic layer 6 is formed on the dielectric layer. And, as shown in FIG. 19, a second through hole 17 is formed inside the insulating portion 16. When the above procedures are followed, no solid
10 electrolytic layer 6 can be formed on the other surface, viz. non-porous surface, of aluminum foil 3.

And then, in the same way as in the embodiment 1, a through hole electrode 7 is formed in the second through hole 17, a collector layer 8 is formed on the solid electrolytic layer 6, and then the insulation layer 5
15 disposed on the aluminum foil 3 is provided with an opening 9 at a certain specific place, and a connection terminal 10 is provided at the opening 9 of insulation layer 5 and on the exposed surface of through hole electrode 7.

Thus in the method of manufacturing SEC in accordance with the present embodiment 4, the reliability in insulation between the through hole
20 electrode 7 and the aluminum foil 3 is improved, and a possible spreading of solid electrolytic material onto the aluminum foil 3 at the opening 9 is prevented, to a sure separation between the positive electrode and the negative electrode.

25 INDUSTRIAL APPLICABILITY

In the method for manufacturing SECs in accordance with the present invention, the connection terminals provided at the opening of insulation

layer and on the exposed surface of through hole electrode, respectively, are disposed on a single flat plane. Thus the present method of manufacture enables to manufacture with ease the large capacitance SECs that can be connected direct with semiconductor components and provide a superior high
5 frequency characteristic.

Claims:

1. A method for manufacturing solid electrolytic capacitor including the steps of:

forming a porous portion on one of the surfaces of an aluminum foil,
forming a dielectric layer on said porous portion,
forming a through hole in said aluminum foil at a certain specific location,

forming an insulation layer on said aluminum foil to cover both the other surface that is opposite to the one having said porous portion and the inner wall surface of said through hole,

forming a solid electrolytic layer on said dielectric layer,

forming a through hole electrode in said through hole, forming a collector layer on said solid electrolytic layer,

forming an opening at a certain specific place of said insulation layer disposed on said aluminum foil, and

providing a connection terminal at said opening and on exposed surface of said through hole electrode, respectively.

2. A method for manufacturing solid electrolytic capacitor including the steps of:

forming a porous portion on one of the surfaces of an aluminum foil,
forming a dielectric layer on said porous portion,
forming a through hole in said aluminum foil at a certain specific location,

forming a resist portion on the other surface of the aluminium foil that is opposite to the one having said porous portion at a certain specific location,

forming an insulation layer on said aluminum foil to cover both the other surface that is opposite to the one having said porous portion and the

inner wall surface of said through hole,

forming a solid electrolytic layer on said dielectric layer,

forming a through hole electrode in said through hole, forming a collector layer on said solid electrolytic layer,

forming an opening in said insulation layer disposed on said aluminum foil at a certain specific location by peeling said resist portion off, and

providing a connection terminal at said opening of said insulation layer and on exposed surface of said through hole electrode, respectively.

3. A method for manufacturing solid electrolytic capacitor including the steps of:

forming a porous portion on one of the surfaces of an aluminum foil,

forming a dielectric layer on said porous portion,

forming a through hole in said aluminum foil at a certain specific location,

forming an insulation layer on said aluminum foil to cover both the other surface that is opposite to the one having said porous portion and the inner wall surface of said through hole,

forming a resist film covering the entire surface of said insulation layer,

forming a solid electrolytic layer on said dielectric layer,

forming a through hole electrode in said through hole,

peeling said resist film off,

forming a collector layer on said solid electrolytic layer,

forming an opening in said insulation layer disposed on said aluminum foil at a certain specific location, and

providing a connection terminal at said opening of said insulation layer and on exposed surface of said through hole electrode, respectively.

4. A method for manufacturing solid electrolytic capacitor including the steps of :

forming a porous portion on one of the surfaces of an aluminum foil, forming a dielectric layer on said porous portion,

forming a through hole in said aluminum foil at a certain specific location,

forming a resist portion on said aluminum foil at a certain specific location,

forming an insulation layer on said aluminum foil to cover both the other surface that is opposite to the one having said porous portion and the inner wall surface of said through hole,

forming a resist film covering the entire surface of said insulation layer,

forming a solid electrolytic layer on said dielectric layer,

forming a through hole electrode in said through hole,

peeling said resist film off,

forming a collector layer on said solid electrolytic layer,

forming an opening in said insulation layer disposed on said aluminum foil at a certain specific location by peeling said resist portion off, and

providing a connection terminal at said opening of said insulation layer and on exposed surface of said through hole electrode, respectively.

5. A method for manufacturing solid electrolytic capacitor including the steps of:

forming a porous portion on one of the surfaces of an aluminum foil,

forming a dielectric layer on said porous portion,

forming a through hole in said aluminum foil at a certain specific location,

forming an insulation layer on said aluminum foil to cover both the other surface that is opposite to the one having said porous portion and the inner wall surface of said through hole,

forming a through hole electrode in said through hole,

forming a solid electrolytic layer on said dielectric layer,

forming a collector layer on said solid electrolytic layer,

forming an opening in said insulation layer disposed on said aluminum foil at a certain specific location, and

providing a connection terminal at said opening of said insulation layer and on exposed surface of said through hole electrode, respectively.

6. A method for manufacturing solid electrolytic capacitor including the steps of:

forming a porous portion on one of the surfaces of an aluminum foil,

forming a dielectric layer on said porous portion,

forming a first through hole in said aluminum foil at a certain specific location,

forming an insulation portion on said aluminum foil to cover the other surface that is opposite to the one having said porous portion and the inside of said first through hole,

forming a solid electrolytic layer on said dielectric layer,

forming a second through hole in said insulation portion,

forming a through hole electrode in said second through hole,

forming a collector layer on said solid electrolytic layer,

forming an opening in said insulation layer disposed on said aluminum foil at a certain specific location, and

providing a connection terminal at said opening of said insulation layer and on exposed surface of said through hole electrode, respectively.

7. The method for manufacturing solid electrolytic capacitor recited in claim 3 or claim 4, wherein

said resist film is formed of either a photo sensitive resin or an adhesive organic film.

8. The method for manufacturing solid electrolytic capacitor recited in claim 3 or claim 4, wherein

said resist film is formed by using one of the methods among an immersing method, a spin coating process, a screen printing method and a film attaching method.

9. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein

said through hole is formed by a process where a photo-resist is applied on both of the surfaces, and it is wet-etched after the resists are patterned.

10. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein

said through hole is formed by using one of the methods among a laser beam machining, a punching method, a drilling method and an electric discharge machining.

11. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein

said insulation layer is provided after edge of said through hole is chamfered.

12. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein

said insulation layer is formed by electrodeposition.

13. The method for manufacturing solid electrolytic capacitor recited in one

of claims 1 through 6, wherein

said insulation layer is consisting of a first layer of an insulating resin and a second layer of an insulating resin formed by mixing a micro gel, carbon particles and titanium oxide particles, electrodeposited.

14. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein

said through hole electrode is formed by first filling said through hole with a conducting adhesive substance and then curing it.

15. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein

said opening is formed by using either a laser beam machining or a grinding method.

16. The method for manufacturing solid electrolytic capacitor recited in claim 5 or 6, wherein

said opening is formed by the process in which a resist portion is provided on non-porous surface of said aluminum foil prior to formation of said insulation layer, and then said resist portion is peeled off after said collector layer is formed.

17. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein

said connection terminal is formed with a conducting adhesive substance.

18. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein said connection terminal is formed by an electroplating or an electroless plating.

19. The method for manufacturing solid electrolytic capacitor recited in one

of claims 1 through 6, wherein

said solid electrolytic layer is formed of a composite material containing at least one among a π electron conjugated polymer and a conducting polymer other than that.

20. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein

said solid electrolyte is a conducting polymer formed by at least one of the processes among the chemical polymerization and the electrolytic polymerization.

21. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein

said solid electrolyte is a conducting polymer formed by applying a suspension of powdered conducting polymer, and drying it, and then electrolytically polymerized.

22. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein

said solid electrolyte is manganese dioxide formed by heat-decomposing manganese nitrate.

23. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein

said solid electrolyte is a conducting polymer formed by electrolytic polymerization after manganese dioxide is obtained by heat-decomposition of manganese nitrate.

24. The method for manufacturing solid electrolytic capacitor recited in one of claims 1 through 6, wherein

said collector layer is formed with a carbon particle suspension and a conducting adhesive substance.